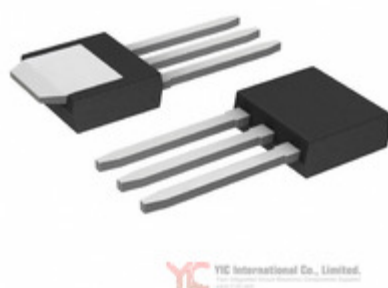

	<p>Hersteller-Teilenummer: NTD6415AN-1G</p>
	<p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p>
	<p>Teil der Beschreibung: MOSFET N-CH 100V 23A IPAK</p>
	<p>Datenblätter:  NTD6415AN-1G.pdf</p>
	<p>RoHs Status: Bleifrei / RoHS-konform</p>
	<p>Lagerzustand: New original, 34363 pcs Stock Available.</p>
	<p>Liefern von: Hong Kong</p>
<p>Image may be representation. See specs for product details.</p>	<p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>

Spezifikationen

Teilenummer	NTD6415AN-1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 100V 23A IPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	34363 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	I-Pak
Verlustleistung (max)	83W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	23A (Tc)
Rds On (Max) @ Id, Vgs	55 mOhm @ 23A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	29nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	700pF @ 25V
Verpackung	Tube



















































NTD6415AN-1G ist neu im Original, Suche NTD6415AN-1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD6415AN-1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD6415AN-1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTD6414ANT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 32A DPAK</p>	 <p>NTD6414AUG ON NTD6414AUG ON</p>	 <p>NTD6415ANL ON NTD6415ANL ON</p>	 <p>NTD6414AN-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 32A IPAK</p>
 <p>NTD6415ANT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 23A DPAK</p>	 <p>NTD6416AN ON NTD6416AN ON</p>	 <p>NTD6415ANLT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 23A DPAK</p>	 <p>NTD6415AN ON NTD6415AN ON</p>

heiße Teile

Mehr

 NTD5867NL-1G	 NTD5867NLG	 NTD5867NLT4G	 NTD5867NT4G	 NTD60N02KG
 NTD60N02R	 NTD60N02R-001	 NTD60N02R-032	 NTD60N02R-035	 NTD60N02R-1G
 NTD60N02R-1R	 NTD60N02R-35G	 NTD60N02RG	 NTD60N02RG-1G	 NTD60N02RT
 NTD60N02RT4	 NTD60N02RT4G	 NTD60N03RT4G	 NTD60N03T4	 NTD60N03T4G
 NTD6414AN	 NTD6414AN-1G	 NTD6414ANT4G	 NTD6414AUG	 NTD6415AN
 NTD6415ANL	 NTD6415ANLT4G	 NTD6415ANT4G	 NTD6416AN	 NTD6416AN-1G
 NTD6416ANG	 NTD6416ANL	 NTD6416ANL-1G	 NTD6416ANLT4G	 NTD6416ANT4G
 NTD65N03G	 NTD65N03R-001	 NTD65N03R-035	 NTD65N03R-1G	 NTD65N03R-35G
 NTD65N03RG	 NTD65N03RT4G	 NTD6600G	 NTD6600N	 NTD6600N-001
 NTD6600N-1G	 NTD6600NT4	 NTD6600NT4G	 NTD70N03	 NTD70N03R

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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